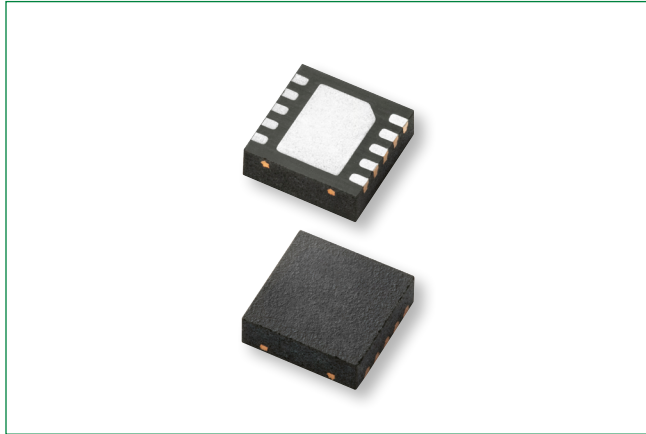


# LS12052BD33

## 18V, 5A eFuse with Over-Voltage Protection and Blocking FET Control

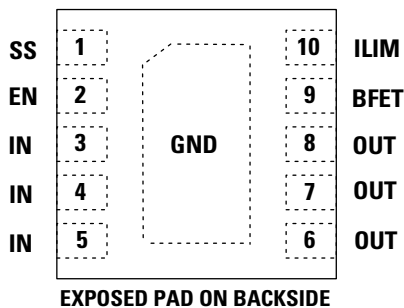


### Web Resources



Download ECAD models, order samples, and find technical resources at [www.littelfuse.com](http://www.littelfuse.com)

### Pinout Designation



### Pin Description

Pin #	Pin Name	Description
3,4,5	IN	Power input pin.
9	BFET	External NFET gate driver. Control an external NFET which can be connected "Back to Back" with the LS12052BD33 output to prevent current flowing from the load to the source. Float this pin if it is not used.
10	ILIM	Current limit program pin. Program the current limit by connecting a resistor to ground.
1	SS	Soft Start time program pin. Connect a capacitor to ground to program the soft start time.
2	EN	Enable interface pin. EN has accurate ON/OFF threshold of 1.29V and 1.19V respectively. Pull it above ON threshold to enable the IC. Pull it below OFF threshold to disable the IC.
6,7,8	OUT	Power output pin.
EP	GND	Ground pin.

### Description

The LS12052BD33 family of integrated load switches provides an easy circuit protection to power the system. The device uses few external components and provides multiple protection modes. They are a robust defense against overload, short circuit, input voltage surge, excessive inrush current and reverse current blocking with an external NFET. The switch's low  $R_{DS(ON)}$  helps to reduce power loss during normal operation. Current limit level can be set with a single external resistor. Input over voltage events are protected by internal clamp circuitry to a safe output voltage. Programmable soft-start controls the slew rate of the output voltage to limit inrush current during plug in. It integrates thermal fold-back function and over temperature shutdown protection. The BFET pin is provided to drive an external NFET which can be connected "Back to Back" with the LS12052BD33 output. The external NFET gate is driven by BFET to prevent current flow from the load to the source. LS12052BD33 is available in small DFN 3mm x 3mm-10 package.

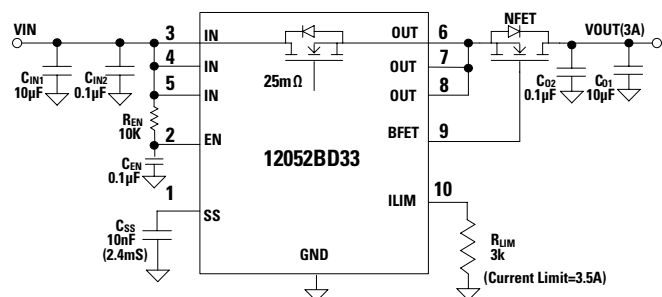
### Features and Benefits

- Wide Input Voltage Range from 2.7V to 18V
- Extremely Low  $R_{DS(ON)}$  for the Integrated Protection Switch: 25mΩ
- External Programmable Soft-Start Time
- External Programmable Current Limit
- Support Reverse Current Blocking
- Short-circuit Protection
- Fixed Over-voltage 14.4V Output Voltage Clamp
- Accurate 1.29V EN Pin Turn-on Threshold
- Thermal Shutdown Protection & Auto Recovery
- DFN3x3\_10L Packages
- Pb-Free and RoHS Compliant

### Applications

- HDD and SSD Drives
- Adapter Powered Devices
- Notebook PC
- PCI, PCIe Cards
- Industry

### Typical Applications



# LS12052BD33

## 18V, 5A eFuse with Over-Voltage Protection and Blocking FET Control

### Absolute Maximum Rating (Reference to GND)

Symbol	Value	Units
$V_{IN}$	-0.3 to +20	V
BFET	-0.3 to $V_{IN}+6$	V
EN	-0.3 to +20	V
The other Pins	-0.3 to +6.5	V
Junction Temperature Range	-40 to +150	°C
Storage Temperature Range	-65 to +150	°C
ESD, Human Body Model (HBM)	±2000	V
Lead Temperature (Soldering 10s)	260	°C

**Notes:** Stress exceeding those listed "Absolute Maximum Ratings" may damage the device.

### Recommend Operating Conditions

Symbol	Value	Units
Input Voltage ( $V_{IN}$ )	+2.7 to +18	V
Junction Temperature Range	+125	°C

**Note:** The device is not guaranteed to function outside of the recommended operating conditions.

### Thermal information

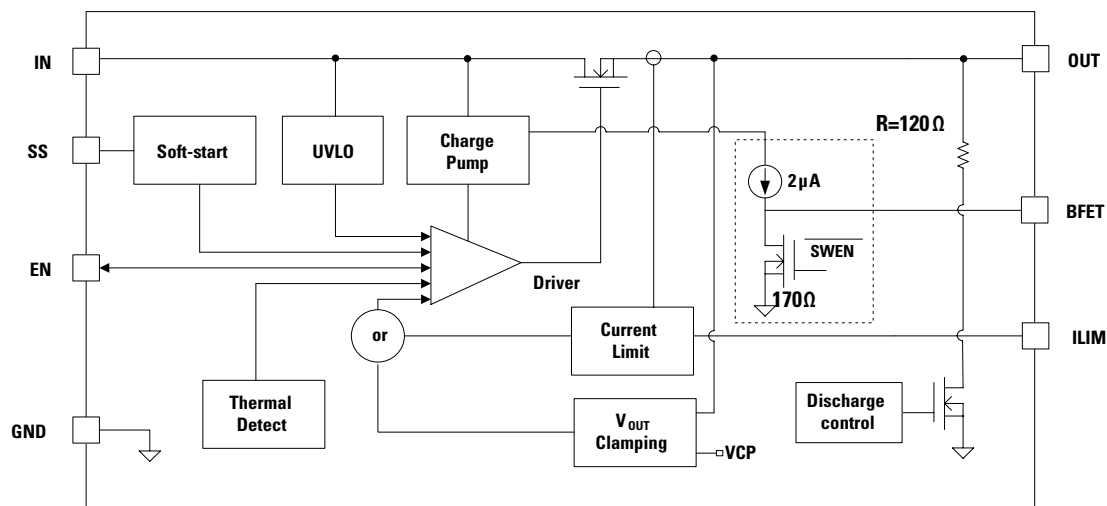
Symbol	Value	Units
Maximum Power Dissipation ( $T_A=25^{\circ}\text{C}$ )	2.6	W
Thermal Resistance ( $\theta_{JA}$ )	38	°C/W
Thermal Resistance ( $\theta_{JC}$ )	8	°C/W

#### Notes:

1. Measured on JESD51-7, 4-Layer PCB.

2. The maximum allowable power dissipation is a function of the maximum junction temperature  $T_{J,MAX}$ , the junction to ambient thermal resistance  $\theta_{JA}$ , and the ambient temperature  $T_A$ . The maximum allowable continuous power dissipation at any ambient temperature is calculated by  $P_{D,MAX} = (T_{J,MAX} - T_A) / \theta_{JA}$ . Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.

### Functional Block Diagram



**LS12052BD33****18V, 5A eFuse with Over-Voltage Protection and Blocking FET Control****Electrical Characteristics ( $T_A = +25^\circ\text{C}$ ,  $V_{IN}=12\text{V}$ ,  $R_{LIM}=10\text{k}\Omega$ ,  $C_{SS}=100\text{nF}$ ,  $C_{IN}=10\mu\text{F}$ , unless otherwise specified)**

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
$V_{IN}$	Input Voltage Range		2.7		18	V
$I_{BIAS}$	Quiescent Current			250	280	$\mu\text{A}$
$I_{SHDN}$	Shutdown Current	$V_{EN}=0\text{V}$		10	13	$\mu\text{A}$
$V_{ENR}$	EN Turn-on Threshold	EN Rising	1.24	1.29	1.34	V
$V_{ENF}$	EN Turn-off Threshold	EN Falling	1.14	1.19	1.24	V
$V_{ENHYS}$	EN Hysteresis			100		mV
$I_{EN}$	EN Input Leakage Current	$0\text{V} \leq V_{EN} \leq 5\text{V}$	-200		200	nA
$R_{OUTdis}$	Output Discharging Resistance	$V_{EN}=0\text{V}$		120		$\Omega$
$V_{CLP}$	Clamping Output Voltage		13.8	14.4	15.0	V
$V_{UVLO}$	Input UVLO Threshold	$V_{IN}$ Rising	3.4	3.6	3.8	V
$V_{HYS}$	UVLO hysteresis	$V_{IN}$ Falling		300		mV
$R_{DS(on)}$	Protection FET RON			25		m $\Omega$
$I_{INLIM}$	Current Limit Program Range		1		5	A
$I_{INLIM}$	Current Limit	$R_{LIM}=10\text{k}\Omega$	0.74	1.05	1.36	A
$K_{LIM}$	Current Limit Setting Factor	$I_{INLIM}=1\text{A}\sim 5\text{A}$	7.4	10.5	13.6	A*k $\Omega$
$T_{SS}$	Soft-start Time	$C_{SS}=100\text{nF}$	20	29	38	msec
		SS float	1.2	1.7	2.2	msec
$I_{BFET}$	BFET Charging current	$V_{BFET}=V_{OUT}$		2		$\mu\text{A}$
$V_{BFET}$	BFET Regulation Voltage			$V_{IN}+4\text{V}$		V
	BFET Clamp Voltage			$V_{OUT}+7.5\text{V}$		V
$R_{BFETdis}$	BFET Discharging Resistor	$V_{EN}=0\text{V}$		170		$\Omega$
$T_{SD}$	Thermal Shutdown Temperature			140		$^\circ\text{C}$
$T_{HYS}$	Thermal Shutdown Hysteresis			20		$^\circ\text{C}$
$T_{LIIM}$	Junction Temperature Regulation			125		$^\circ\text{C}$

# LS12052BD33

## 18V, 5A eFuse with Over-Voltage Protection and Blocking FET Control

Typical Performance Characteristics ( $C_{IN}=10\mu F$ ,  $C_{OUT}=10\mu F$ ,  $C_{SS}=10nF$ ,  $T_A=+25^\circ C$ )

Figure 1. Current Limit Vs Rlimit

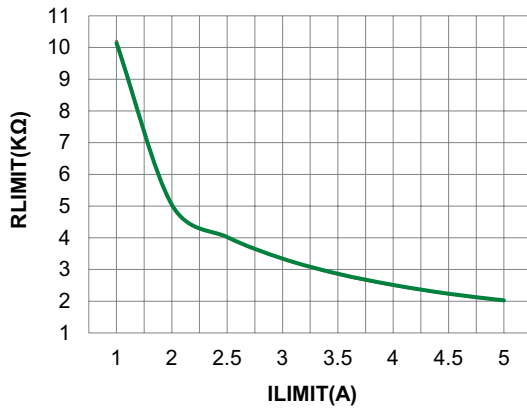


Figure 2. Programmable Current Limit (RLIM=3.3K)

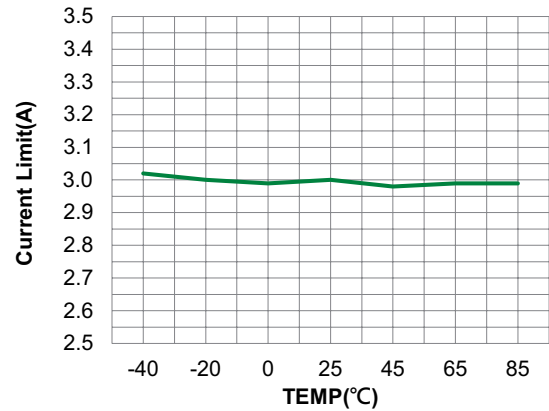


Figure 3. Vin Power On

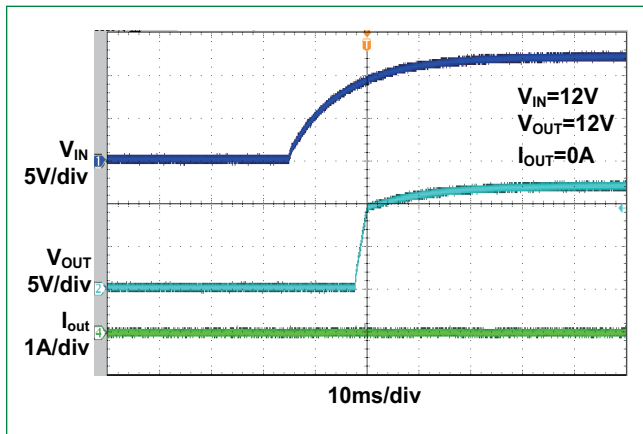
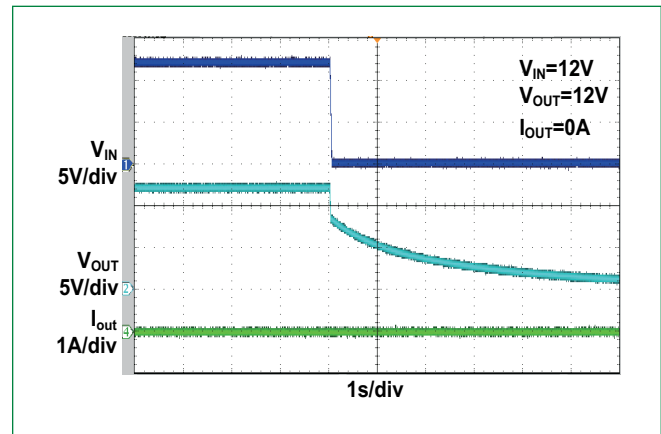
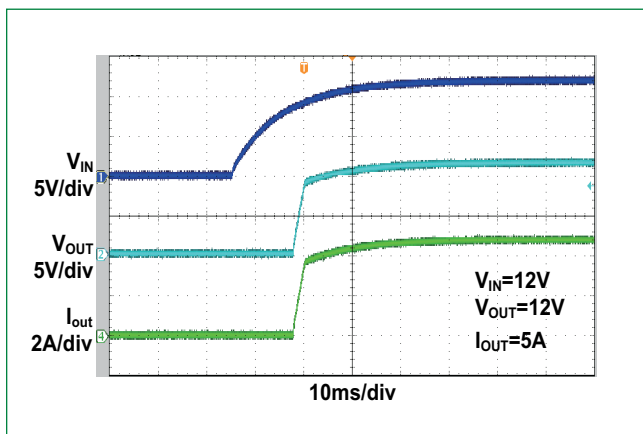


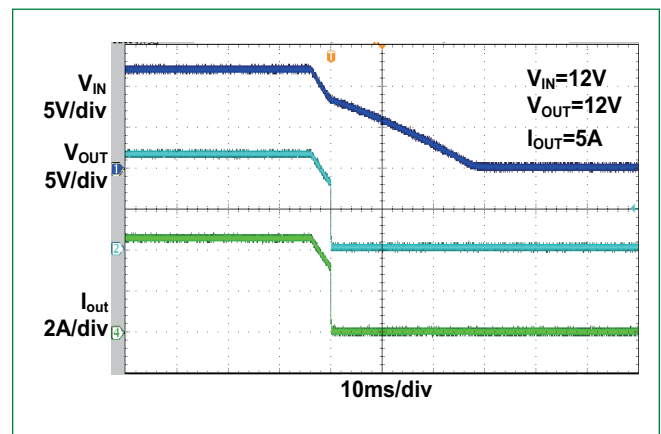
Figure 4. Vin Power Off



Vin Power On



Vin Power Off



# LS12052BD33

## 18V, 5A eFuse with Over-Voltage Protection and Blocking FET Control

Figure 5. EN Power On

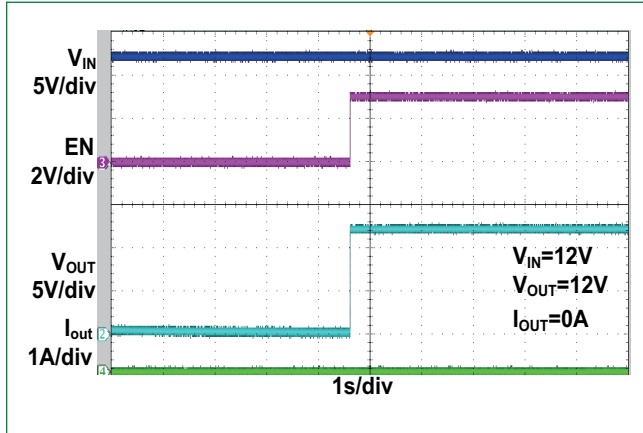


Figure 6. EN Power Off

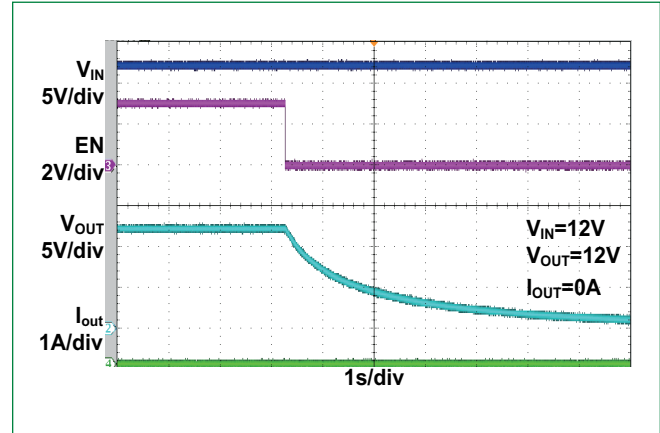


Figure 7. EN Power On

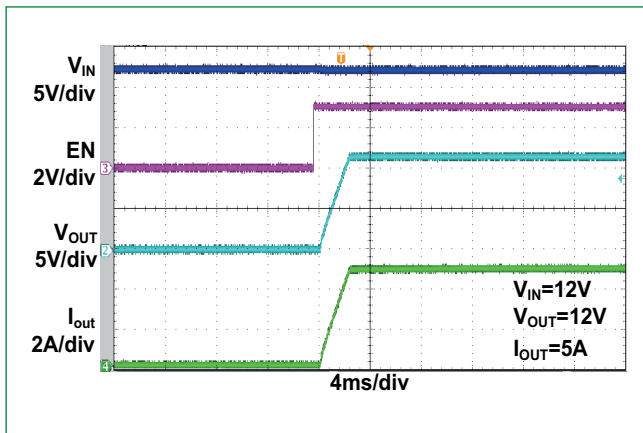


Figure 8. EN Power Off

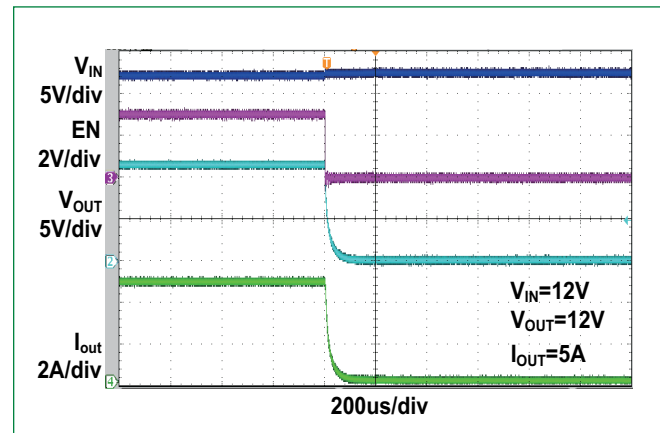
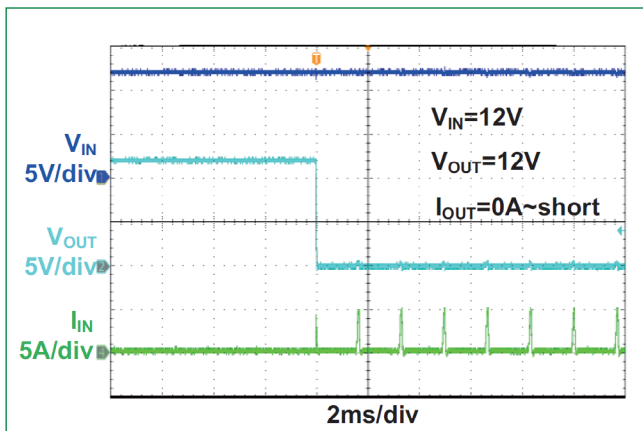


Figure 8. Short Protection



# LS12052BD33

## 18V, 5A eFuse with Over-Voltage Protection and Blocking FET Control

Figure 9. Soft Start Time

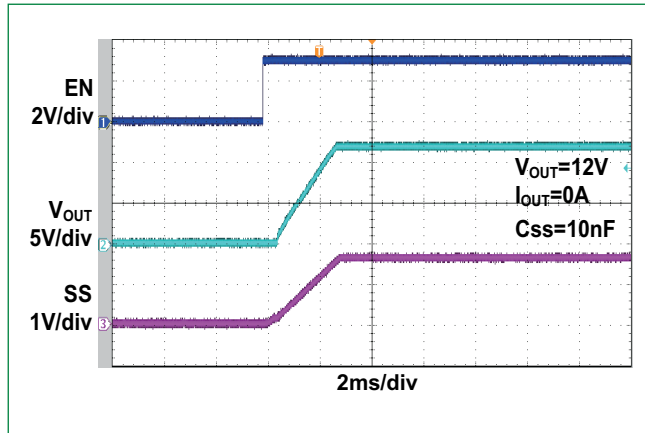


Figure 10. Soft Start Time

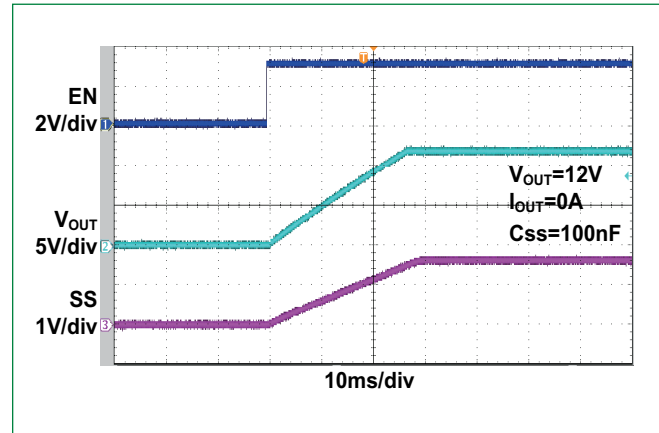


Figure 11. Turnoff Delay to BFET

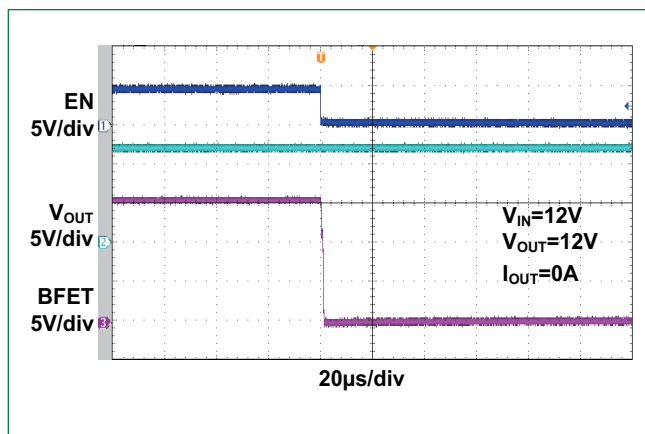
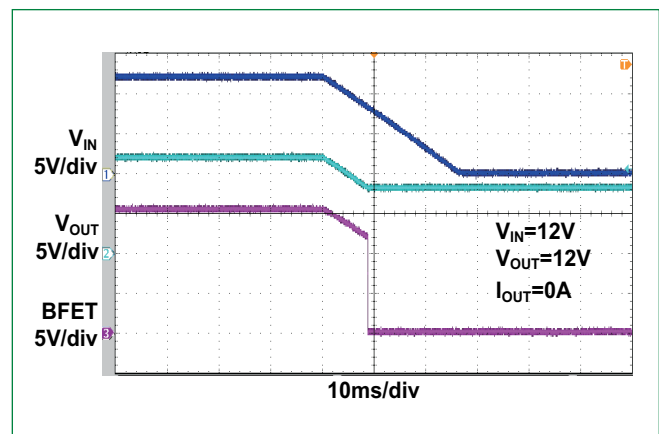


Figure 12. Turnoff Delay to BFET



## Detailed Description

The LS12052BD33 is a current limit load switch with integrated power switch that is used to manage current/voltage/start-up voltage ramp to the connected load. A high level on EN pin enables the internal MOSFET. As  $V_{IN}$  rises, the internal MOSFET of the device will start conducting and allow current to flow from IN to OUT. When EN is held low, internal MOSFET is turned off. User also has the ability to control the output voltage ramp time by connecting a program capacitor between SS pin and GND. After a successful start-up sequence, the device will actively monitor its load current and input voltage, ensuring that the overload current limit  $I_{LIMT}$  programmed by pin  $I_{LIMT}$  is not exceeded. It also monitor input voltage and ensures any spikes are safely clamped to pre-determined level at the output. This keeps the output device safe from harmful voltage and current transients. The device also has built-in thermal sensor. In the event device temperature ( $T_J$ ) exceeds thermal regulation point, current limit will be decreased until the die junction temperature  $T_J$  is regulated at  $T_{LIM}$  125°C. When device temperature ( $T_J$ ) exceeds  $T_{SD}$ , typically 140°C, the thermal shutdown circuitry will shut down the internal MOSFET thereby disconnecting the load from the supply. The LS12052BD33 device will remain off during a cooling period until device temperature falls below  $T_{SD}-20^\circ\text{C}$ , after which it will attempt to restart.

# LS12052BD33

## 18V, 5A eFuse with Over-Voltage Protection and Blocking FET Control

### Application Information

#### Input and Output Capacitor Selection

Recommend to bypass IN and OUT to GND with 10μF ceramic capacitor for the most application. X7R type ceramic capacitors are recommended.

#### Enable and External Programmable Input UVLO

Enable interface pin EN has accurate ON/OFF threshold of 1.29V and 1.19V respectively. An external resistor divider connected from IN to GND can set the VIN under-voltage lockout threshold for load switch operation. EN controls both the ON/OFF state of the internal MOSFET and the external blocking FET. Set EN voltage above ON threshold to enable the internal MOSFET and charge up the gate voltage BFET of external FET. Pull EN below OFF threshold to turn off the internal MOSFET and pull down the gate of the external FET, and Output V<sub>OUT</sub> will be discharged to GND through the internal 120Ω discharging resistor.

#### Soft Start

Connect a program capacitor from this pin to GND to control the slew rate of the output voltage at power-on. This pin can be left floating to obtain a predetermined slew rate (minimum T<sub>SS</sub>) on the output. The soft start time with different capacitor is below:

$$T_{SS} = \begin{cases} T_{SS_{INT}}, & \text{No external } C_{SS} \\ \frac{C_{SS}}{I_{INT}}, & T_{SS} > T_{SS_{INT}} \end{cases}$$

SS cap (nF)	None	10	55	100
Rise time (msec)	1.7	2.4	14	29

Where, T<sub>SS\_INT</sub> is the internally default soft-start time (typical 1.7ms) without an external C<sub>SS</sub>, and I<sub>INT</sub> is the internal current source, about 3.6μA.

#### Output Clamp voltage

LS12052BD33 Output clamp voltage is clamped to 14.4V during the input over-voltage fault event.

Part Number	V <sub>IN</sub>		Clamping Threshold		
			Min	Typ	Max
LS12052BD33	12V	>15V	13.8V	14.4V	15.0V

#### Input Current Limit

For current limited adaptor or sources, user can program the input current limit level to prevent the load current overload the source. When the input current limit loop is engaged, input current will be automatically reduced to the programmed level to satisfy the limited input power.

Input current limit can be programmed with below equation:

$$I_{INLIM} = \frac{10.5A * k\Omega}{R_{ILIM}}$$

Where R<sub>LIM</sub> is the program resistor at the I<sub>LIM</sub> pin.

Program Current Limit Resistance (kΩ)	10.5	5.2	4.2	3.5	3	2.7	2.4	2.1
Current Limit I <sub>INLIM</sub> (A)	1	2	2.5	3	3.5	4	4.5	5





# LS12052BD33

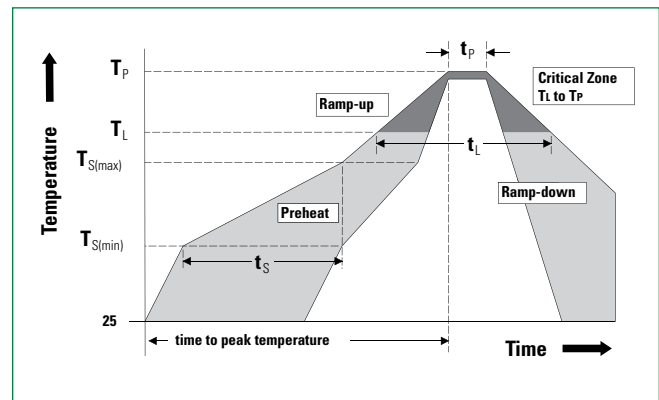
## 18V, 5A eFuse with Over-Voltage Protection and Blocking FET Control

### EVB BOM List

Qty	Ref	Value	Description	Package
1	C <sub>IN1</sub>	10μF	Ceramic Capacitor, 10V, X5R	0805
1	C <sub>O1</sub>	10μF	Ceramic Capacitor, 10V, X5R	0805
3	C <sub>IN2</sub> , C <sub>O2</sub> , Cen	0.1μF	Ceramic Capacitor, 10V, X5R	0603
1	R <sub>en</sub>	10KΩ	Resistor, ±1%	0603
1	C <sub>SS</sub>	10nF	Ceramic Capacitor, 10V, X5R	0603
1	R <sub>LIM</sub>	3KΩ	Resistor, ±1%	0603
1	NFET	MSG040N03G	RDSON (MAX.) =6mΩ	DFN 3x3_8L
1	U1	LS12052BD33	Load Switch IC	DFN3x3_10L

### Soldering Parameters

Average ramp up rate (Tsmin to T <sub>p</sub> )		1~2°C/second, 3°C/second max.
Preheat & Soak	- Temperature Min (T <sub>s(min)</sub> )	150°C
	- Temperature Max (T <sub>s(max)</sub> )	200°C
	- Time (min to max) (t <sub>s</sub> )	60 – 120 secs
Time maintained above	- Temperature(T <sub>L</sub> )	217°C
	- Time(t <sub>L</sub> )	60~150 seconds
Peak Temperature (T <sub>p</sub> )		See Classification Temp intable1
Time within 5°C of actual peak Temperature (t <sub>p</sub> )		30 seconds max
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T <sub>p</sub> )		8 minutes Max.



#### Notes:

1. Tolerance for peak profile Temperature(T<sub>p</sub>) is defined as a supplier minimum and a user maximum.
2. Tolerance for time at peak profile temperature (t<sub>p</sub>) is defined as a supplier minimum and a user maximum.

### Ordering Information

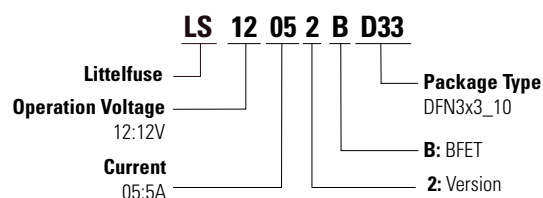
Part Number	Marking	Package	Min. Order Qty.
LS12052DB33	12052B	DFN3x3_10L	5000/Tape & Reel

### Pb-freeProcess – Classification Temperatures (TC)

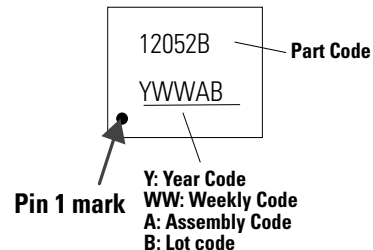
Package Thickness	Volume mm <sup>3</sup> <350	Volume mm <sup>3</sup> 350-2000	Volume mm <sup>3</sup> >2000
<1.6mm	260°C	260°C	260°C
1.6mm–2.5mm	260°C	250°C	245°C
>2.5mm	250°C	245°C	245°C

**Note:** For all temperature information, please refer to topside of the package, measured on the package body surface..

### Part Numbering



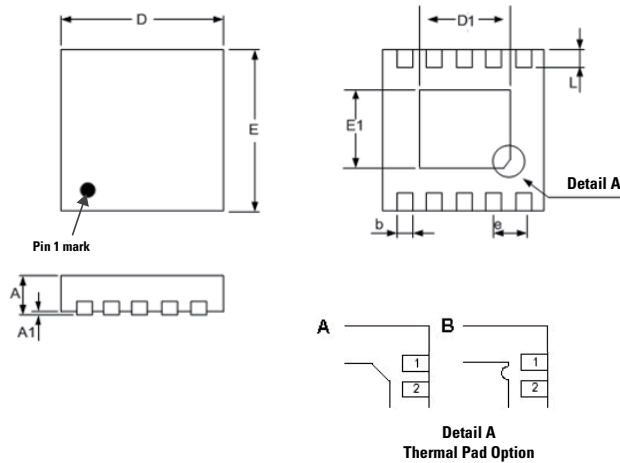
### Part Marking



# LS12052BD33

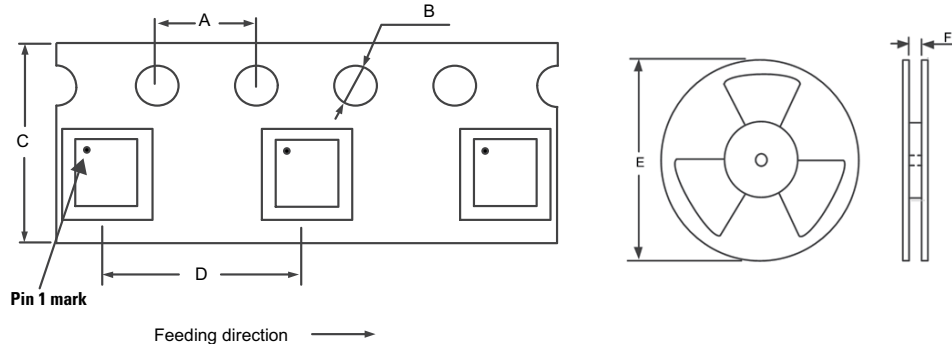
## 18V, 5A eFuse with Over-Voltage Protection and Blocking FET Control

### Dimensions — DFN3x3\_10L



Dimension	Millimeters		Inches	
	Min	Max	Min	Max
A	0.70	0.80	0.028	0.031
A1	0.00	0.05	0.000	0.002
b	0.18	0.30	0.007	0.012
D	2.90	3.10	0.114	0.122
D1	2.10	2.60	0.083	0.102
E	2.90	3.10	0.114	0.122
E1	1.35	1.75	0.053	0.069
e	0.50		0.020	
L	0.30	0.50	0.012	0.020

### Carrier Tape & Reel Specification — DFN3x3\_10L



Symbol	Millimeters
<b>A</b>	4.0
<b>B</b>	1.5
<b>C</b>	12.0
<b>D</b>	8.0
<b>E</b>	13 inch
<b>F</b>	13.0

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**LS12052BD33****18V, 5A eFuse with Over-Voltage Protection and Blocking FET Control****LS12052BD33 Protection IC product family revision history**

Revision number	Comment Date	Description (by number)	Remarks
V1	27-Oct-25	as PM Simon request, Please add a line under IINLIM: IINLIM Current Limit RLIM=10kΩ 0.74 (min), 1.05, 1.36 (max) A	Justin Li
V2	17-Nov-25	as PM Simon request, Please remove the line under IINLIM: IINLIM Current Limit RLIM=2.7kΩ 3.6 (min), 4, 4.5 (max) A	Justin Li